



FRAUNHOFER - Solar Cell Manufacturing & Characterization

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www.ise.fraunhofer.de

Fraunhofer Infrastructure in for VIPERLAB

Characterization @ ISE (Freiburg)

- **IV analyses** with optimizes sun simulators
- **External Quantum Efficiency (EQE)** Setups, optimized for tandem solar cells
- Camera-based **luminescence imaging** for tandems (up to 210mmx210mm) @450nm and 808nm
- Camera-based **lock-in thermography** with illumination at different wavelengths (470 nm, 655 nm, 950 nm) or external voltage
- **Microscopic photoluminescence spectroscopy** via confocal microscopy with various excitation wavelengths (532 nm, 640 nm, 905 nm) and high spatial resolution (approx. 1µm).

Nano-Analytics @ CSP (Halle)

- **Fabrication of specific test structures** and devices (laser processing, soldering, lamination/encapsulation) Defect localization at module level (EL, LIT, EQE, PL, Raman, Microscopy, X-ray tomography)
- **Target preparation** (metallography, fs/ps/ns-laser preparation, FIB techniques)
- LED **SoSim** & High Resolution **Hyper Spectral Imaging**
- **Micro analysis** (SEM/EDS/EBSD/EBIC, µLBIC, electrical and optical micro characterization, ICPMS, LIBS)
- High resolution **nano-analytics** (TEM, TOFSIMS, XPS/UPS, AES, ISS)

PeroLab @ ISE (Freiburg)

- High efficiency silicon **bottom solar cells**
- **Vacuum deposition technologies:** TCO and selective contact sputtering, evaporation (metal, organics, metal oxides), ALD (SnOx, AlOx, ZTO ...).
- **Vacuum deposition** of perovskite absorbers, also **hybrid processing**
- **Wet chemical processing** of perovskite solar cells
- Perovskite silicon tandem solar **cell base lines**
- Range of **metallisation** concepts
- Electrically conductive **adhesive bonding** for low-T interconnection for later module incorporation
- Processing is possible throughout for sample sizes of up to 156x156 mm².

Fraunhofer ISE

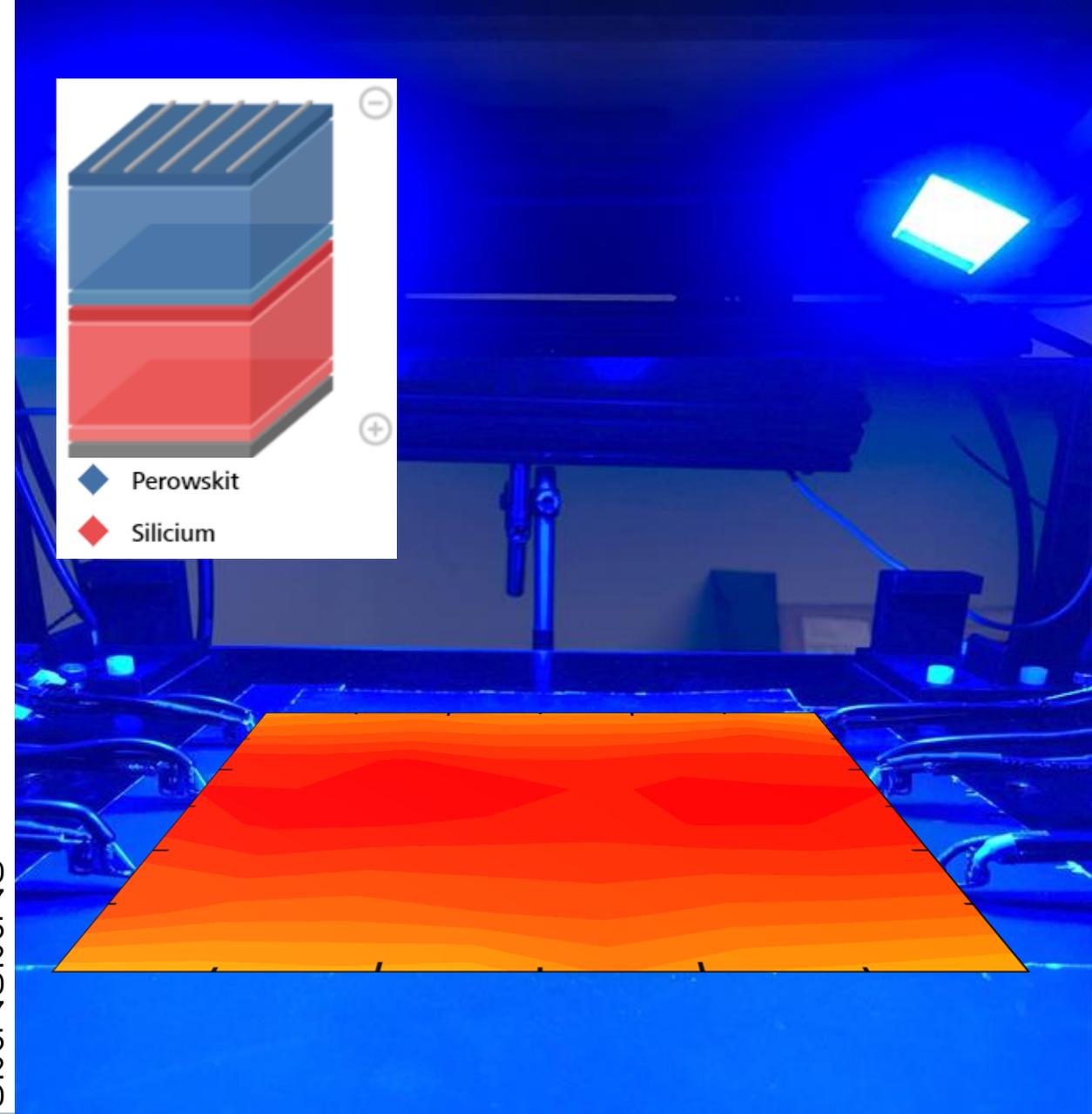
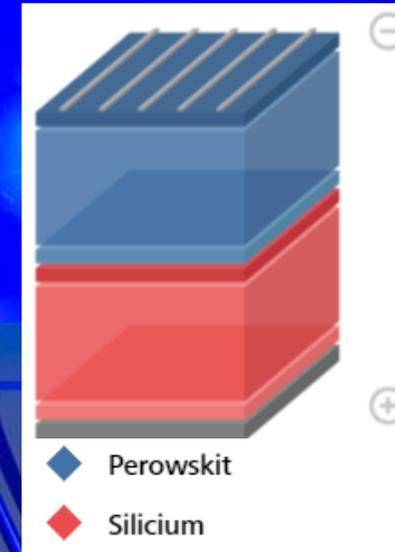
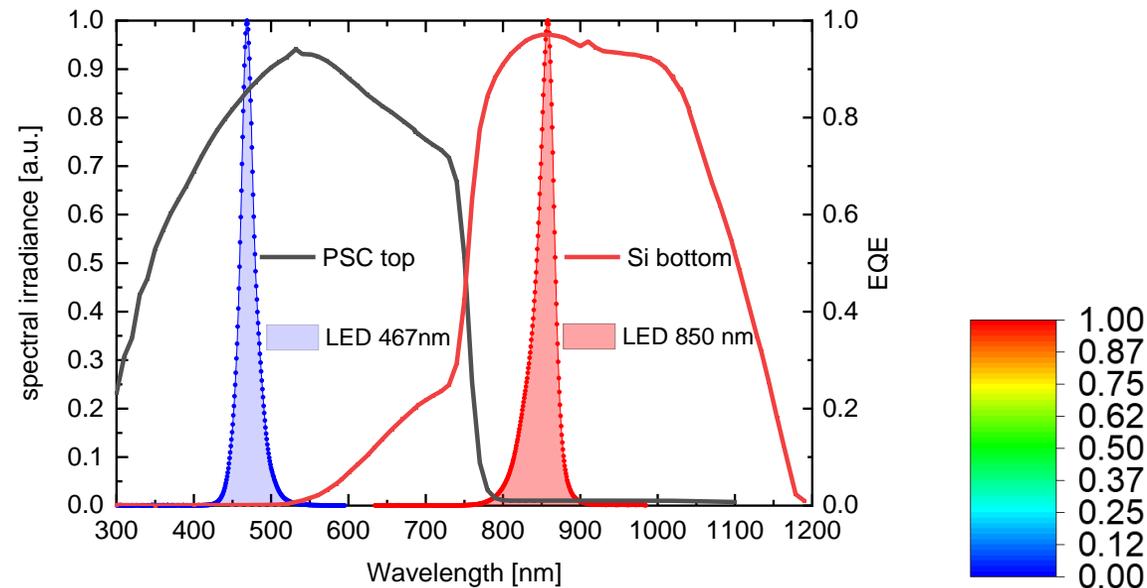
Characterization of Pero(tandem) solar cells

Analysis of Perovskite Silicon Solar Cells

Precise Cell Measurements

Global cell parameters

- External quantum efficiency with homogeneous bias and tunable laser illumination



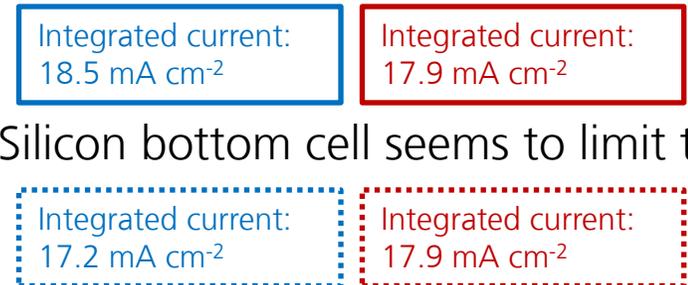
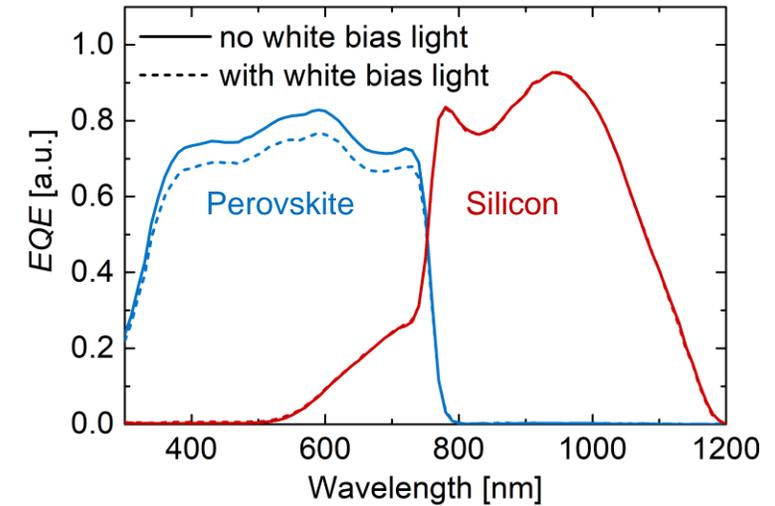
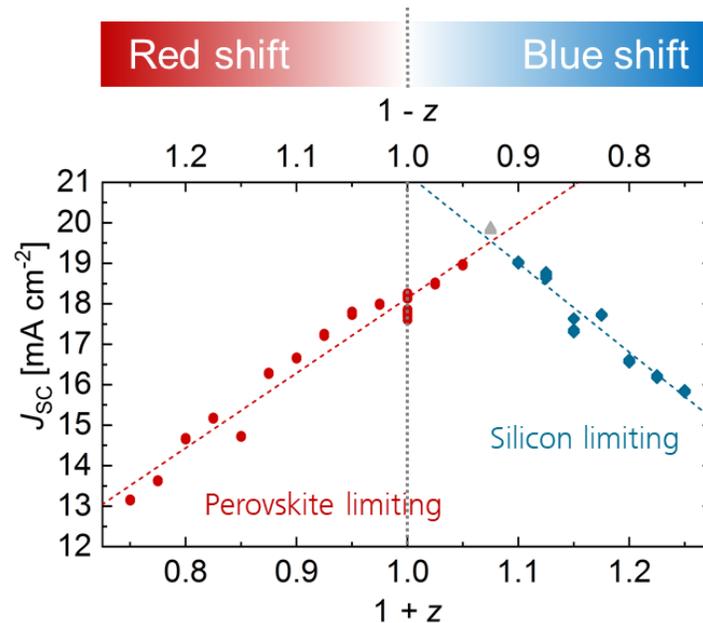
Analysis of Perovskite Silicon Solar Cells

Precise Cell Measurements

Global cell parameters

- External quantum efficiency with homogeneous bias and tunable laser illumination
- Spectral metric analyses

→ Spectral metric analysis needed for correct determination of current matching point



→ Silicon bottom cell seems to limit the cell

→ Perovskite top cell seems to limit the cell

Analysis of Perovskite Silicon Solar Cells

Precise Cell Measurements

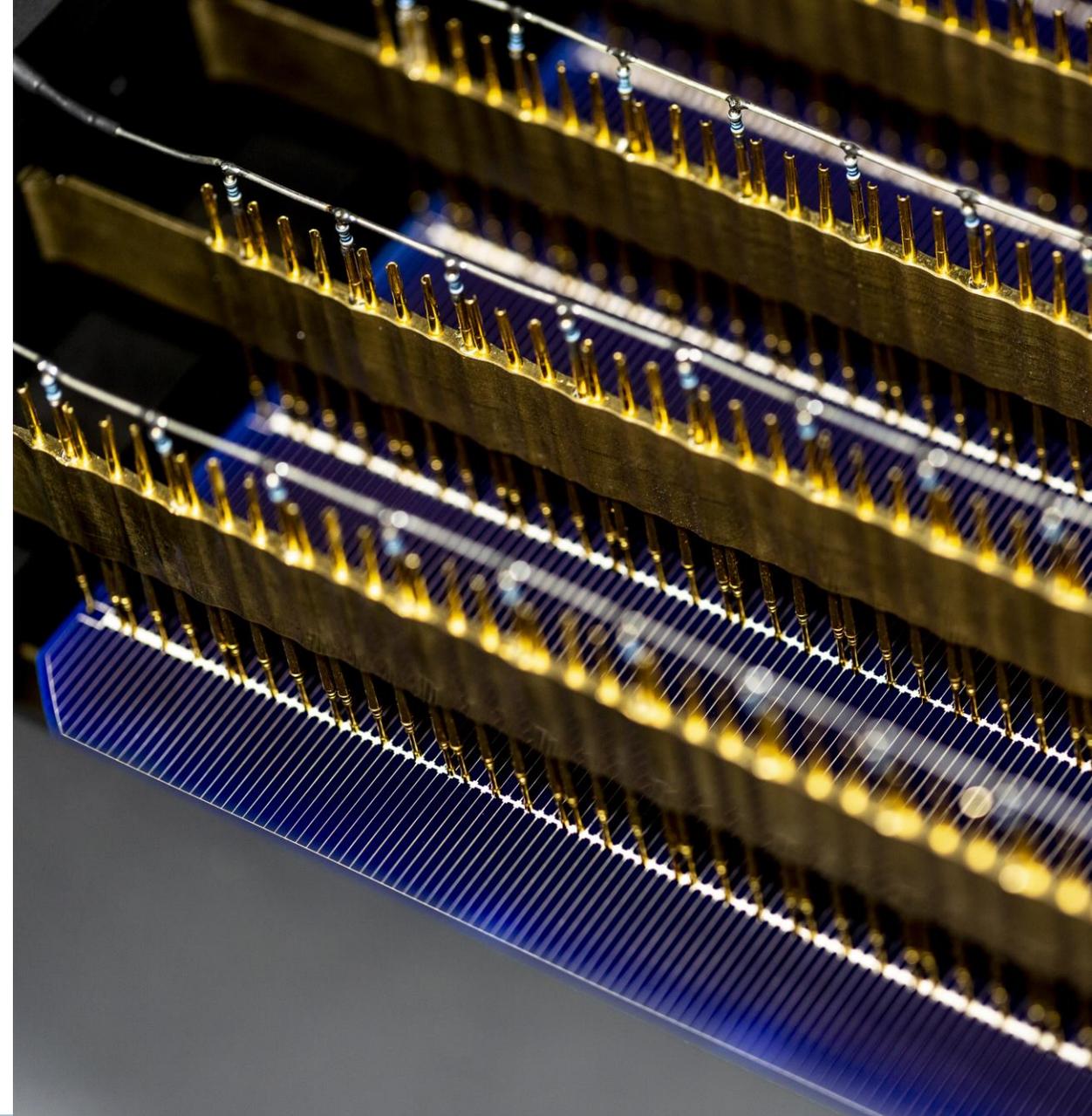
Calibration of Pero-Si tandem solar cells (beyond Viperlab Infrastructure)

- Regular cell calibrations at Fraunhofer ISE Callab Cells
- Calibration of small but also large cells (>16x16cm²)

<https://www.ise.fraunhofer.de/en/rd-infrastructure/accredited-labs/callab/callab-pv-cells.html>

cells@callab.de

Callab
PV Cells

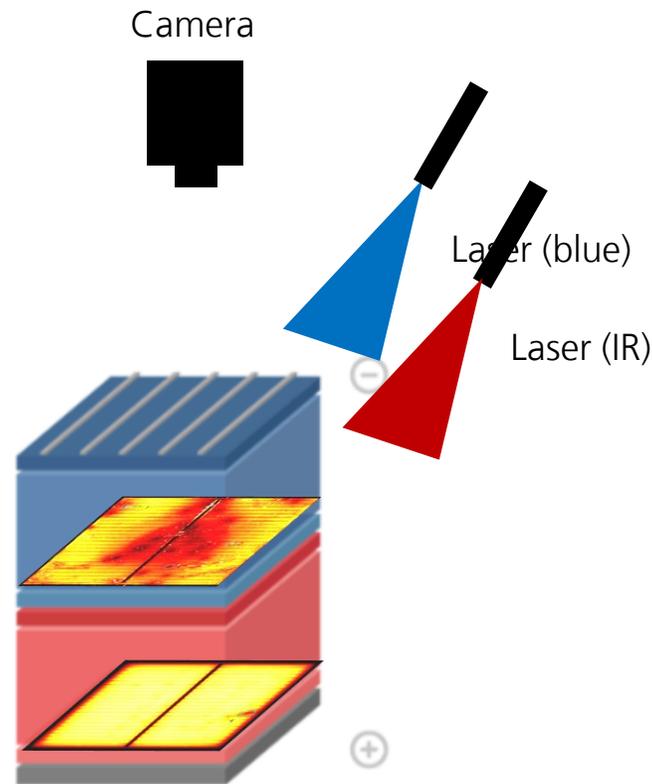


Analysis of Perovskite Silicon Solar Cells

Analysis of Sub Cell Inhomogeneities

PL Imaging for tandem solar cells

- Own development for tandem-optimized setup
- Selective sub-cell excitation and detection
- Camera based measurements to analyse
 - Layer homogeneities
 - Material quality
 - Local voltage
 - Resistance distribution

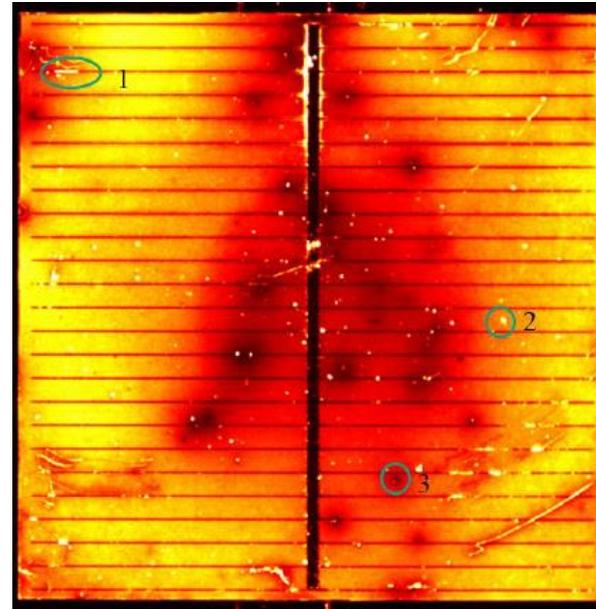


Analysis of Perovskite Silicon Solar Cells

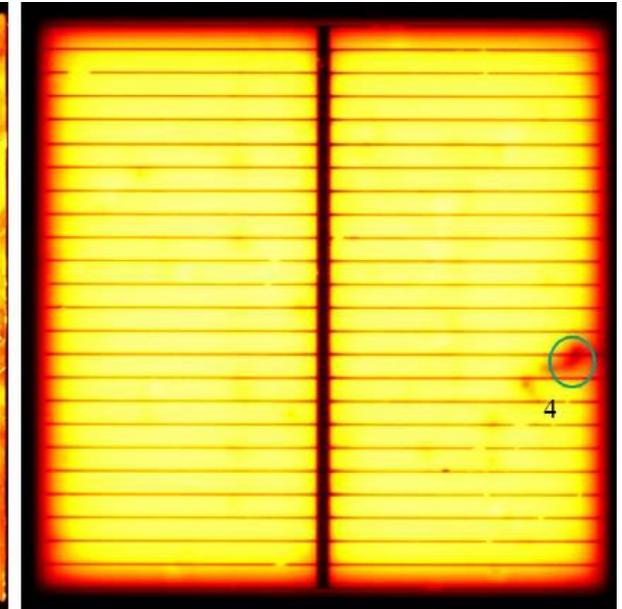
Analysis of Sub Cell Losses

PL Imaging for tandem solar cells

- Own development for tandem-optimized setup
- Selective sub-cell excitation and detection
- Camera based measurements to analyse
 - Layer homogeneities
 - Material quality
 - Local voltage
 - Resistive losses



PLI Perovskite sub cell



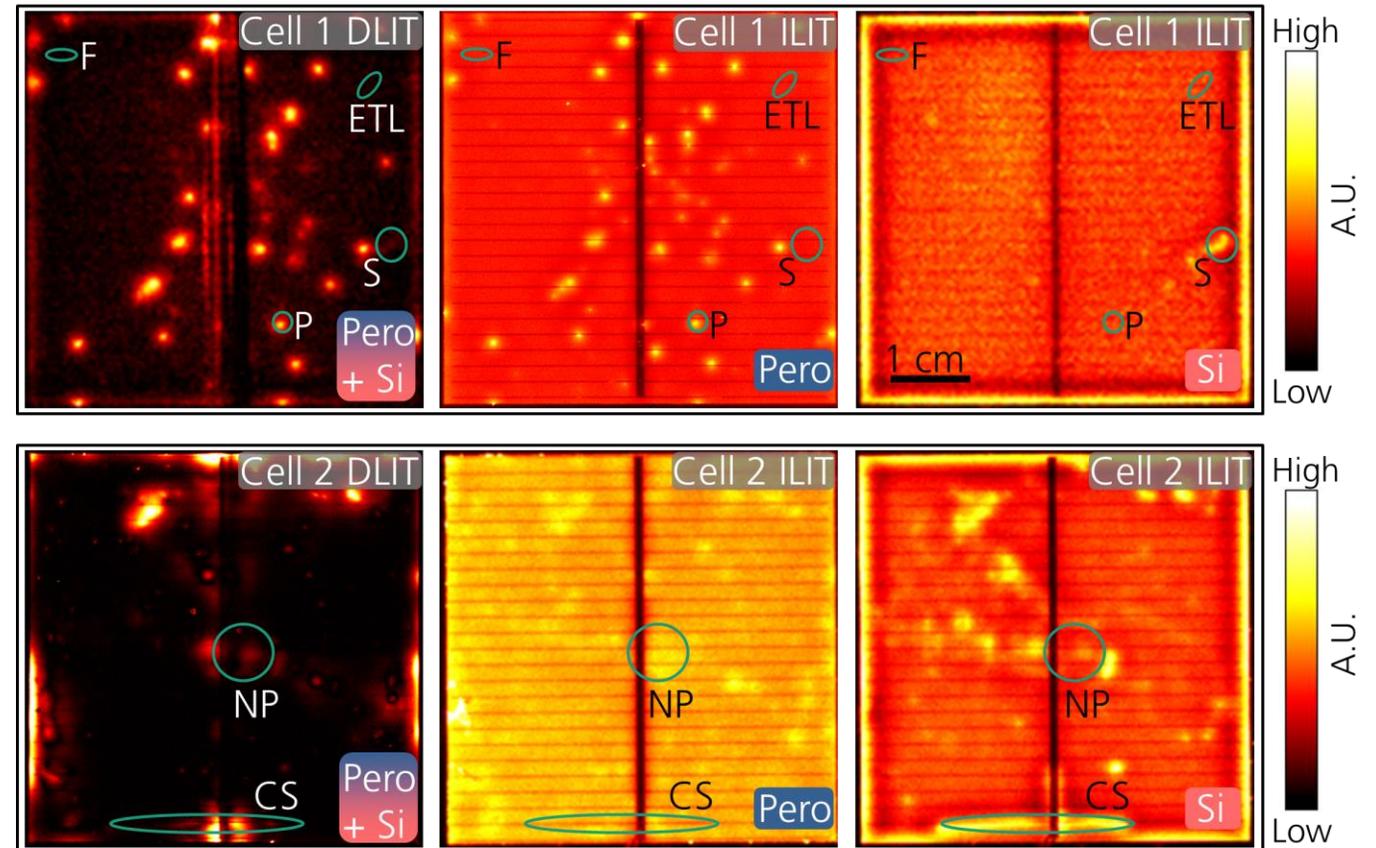
PLI Silicon sub cell

Analysis of Perovskite Silicon Solar Cells

Analysis of Sub Cell Inhomogeneities

Lock-in thermography for tandem solar cells

- Camera-based lock-in thermography with illumination at different wavelengths (470 nm, 655 nm, 950 nm) or external voltage

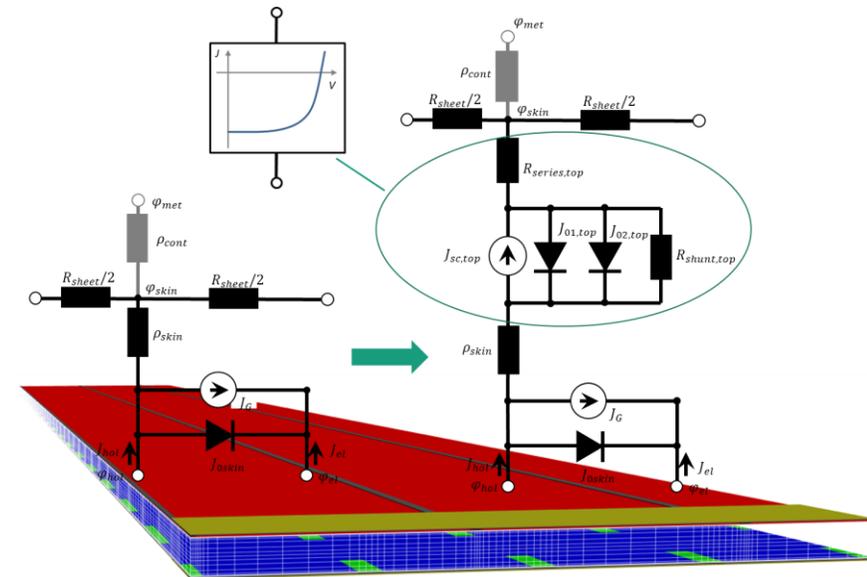
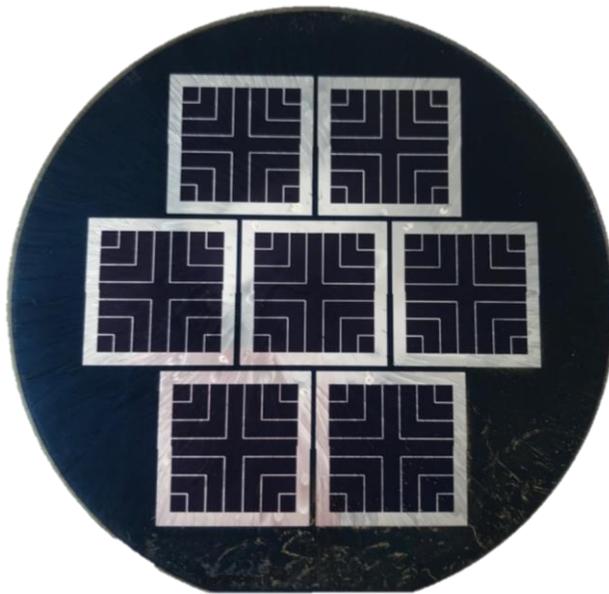


Analysis of Perovskite Silicon Solar Cells

Modeling for Cell Optimization

Quokka3 based modeling of lateral effects

- Edge losses
- Optimum contacting
- Local inhomogeneities and impact on global cell measurements

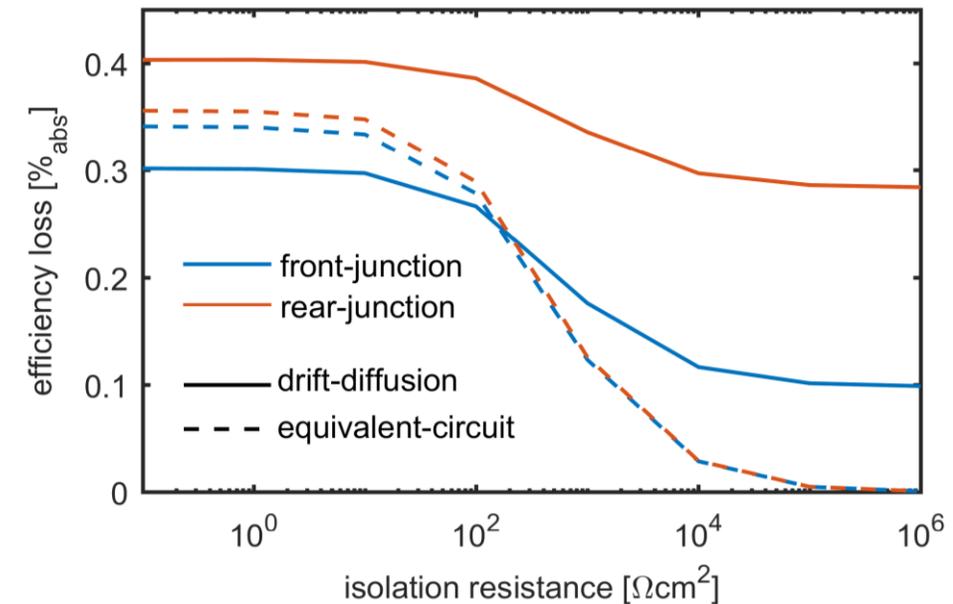
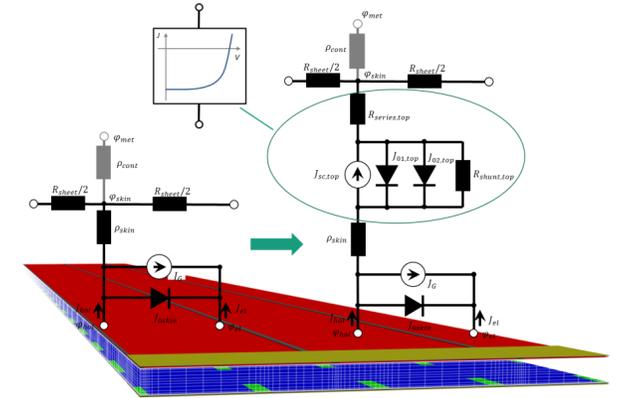
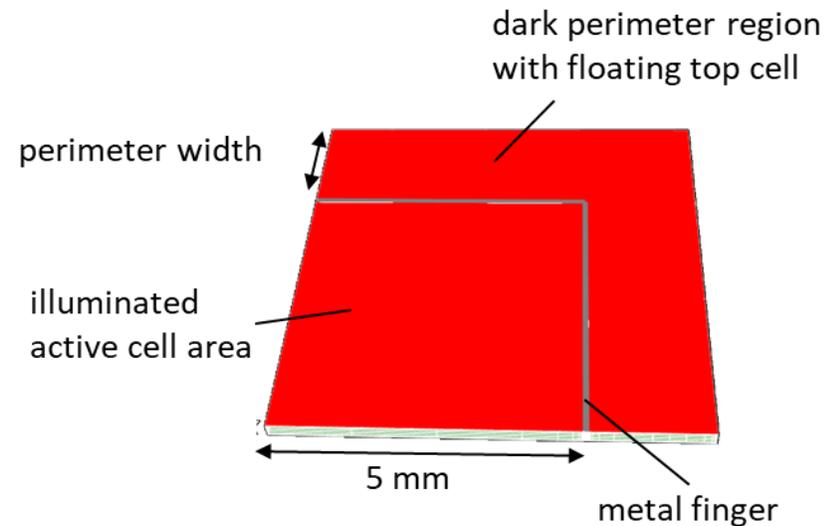
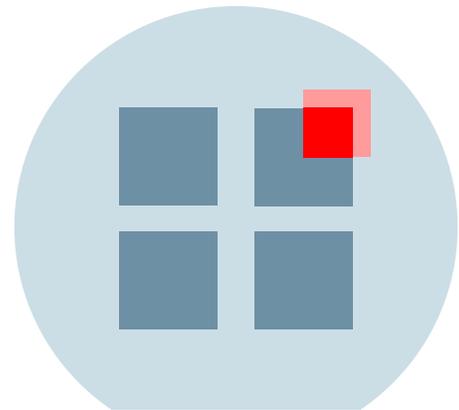


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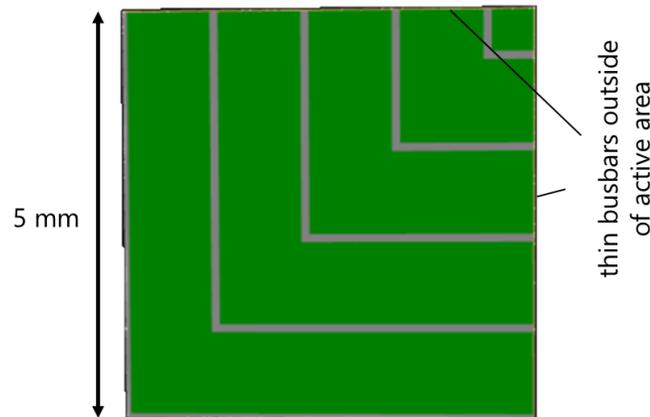
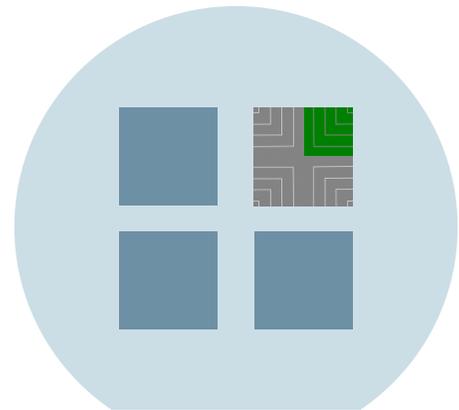
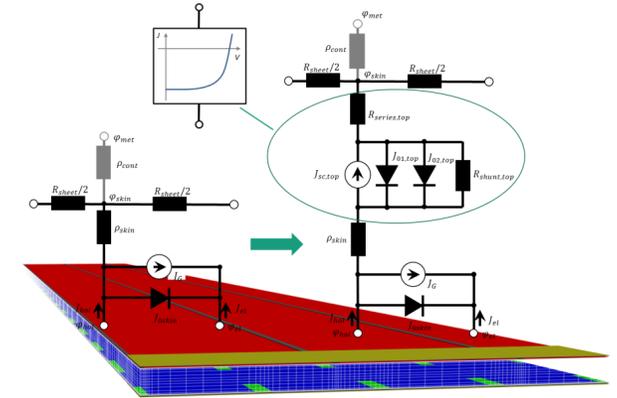


Analysis of Perovskite Silicon Solar Cells

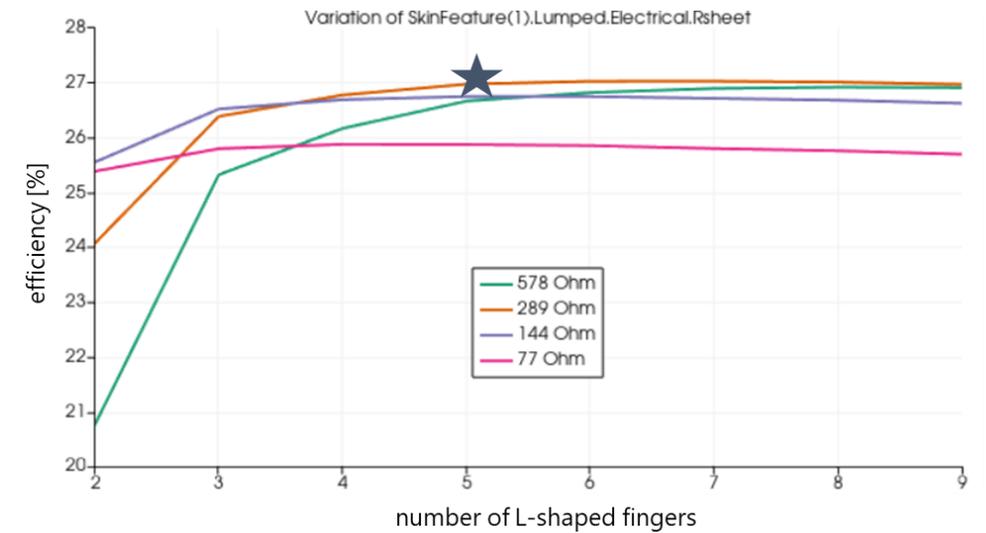
Modeling for Cell Optimization

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Optimum: 27% @ 5 fingers and 20 nm TCO thickness

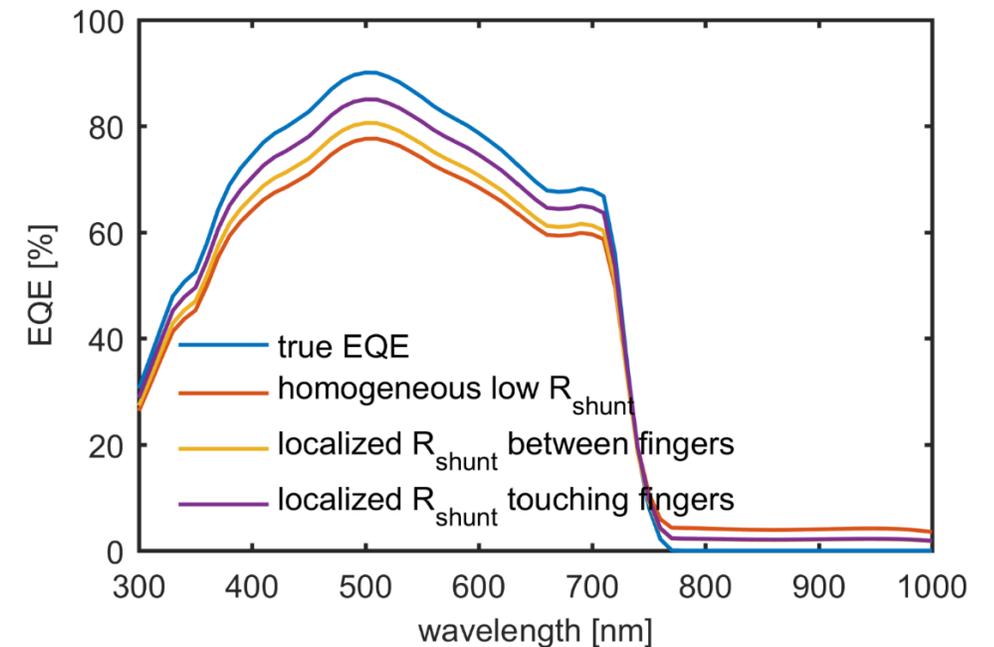
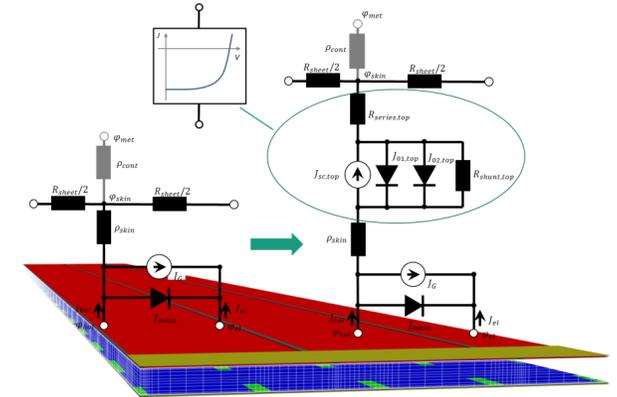
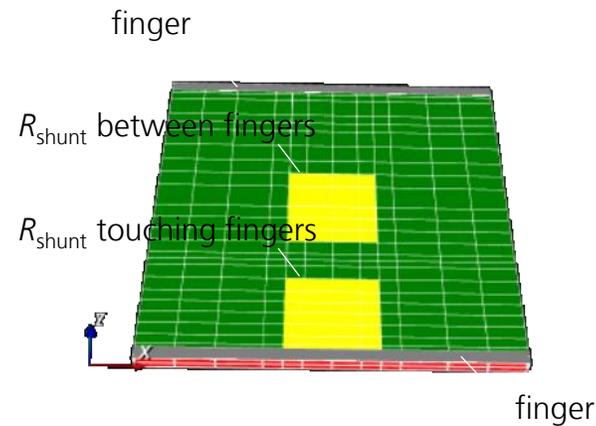
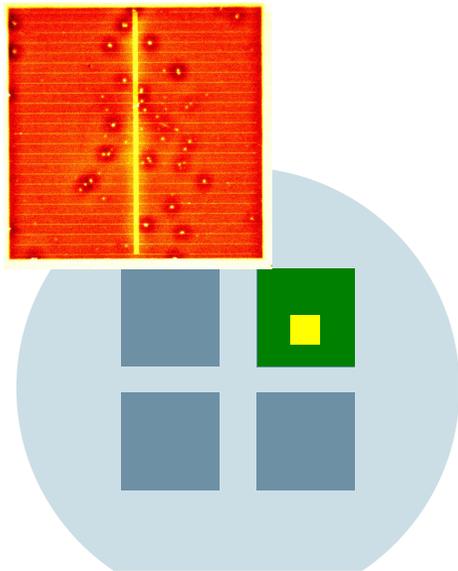


Analysis of Perovskite Silicon Solar Cells

Modeling for Cell Optimization

Quokka3 based modeling of lateral effects

- Edge losses
- Optimum contacting
- **Local inhomogeneities and impact on global cell measurements**



Analysis of Perovskite Silicon Solar Cells

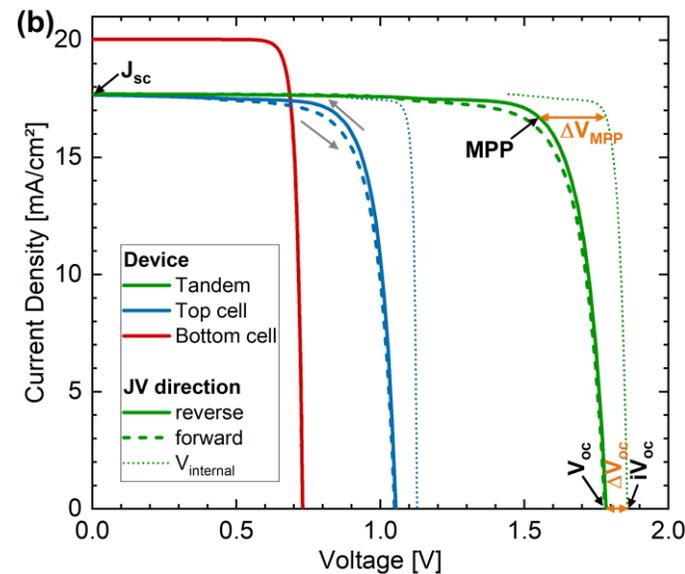
Modeling for Cell Optimization

Quokka3 based modeling of lateral effects

- Edge losses
- Optimum contacting
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Sentaurus based modeling including detailed cell physics

- Transient effects
- Cell efficiency potential, technology comparisons
- Cell optimization



Analysis of Perovskite Silicon Solar Cells

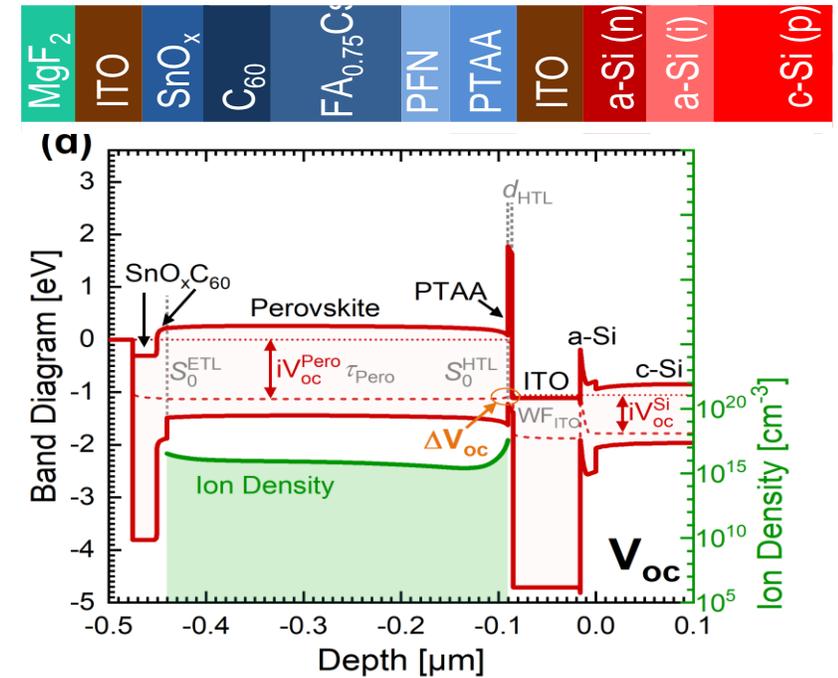
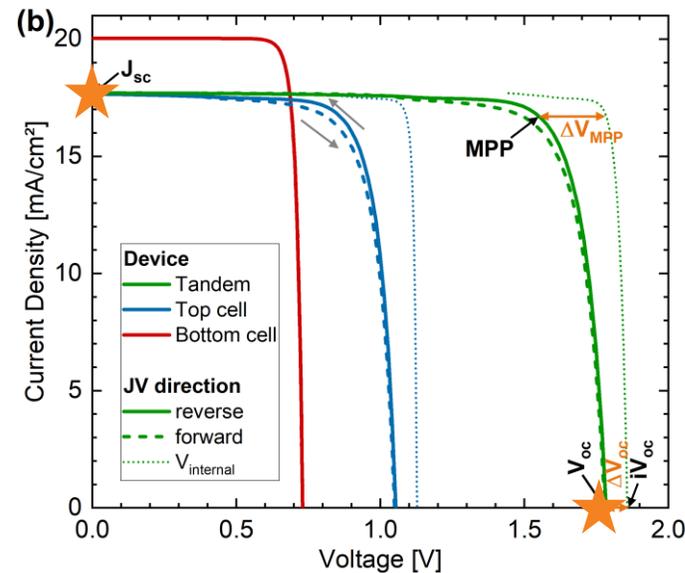
Modeling for Cell Optimization

Quokka3 based modeling of lateral effects

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Fraunhofer CSP

Metrology for Thin Layers

Metrology for Thin Layers

Sample Handling

Glovebox

Thin films can be sensitive to moisture and oxygen. Usually, nitrogen-filled gloveboxes are used for perovskite cell preparation.

Problem

- Oxidation and hydrolysis can occur
- Electronic surface properties change and analytical results can be affected

Approach

- Sample transfer protocol for perovskites and organic layers
- Shipment in air-tight containers
- Handling and sample-preparation in a glovebox
- Inert transfer system for transport between glovebox and XPS/UPS or ToF-SIMS

Glovebox with port for inert sample transfer to analytic facilities



Metrology for Thin Layers

Sample Preparation

Focused Ion Beam

Problem

- Sample preparation is a crucial step and often limits the quality of the measurement
- Traditional (mechanical) methods are slow, not site-specific, sensitive to failures and produce small samples only

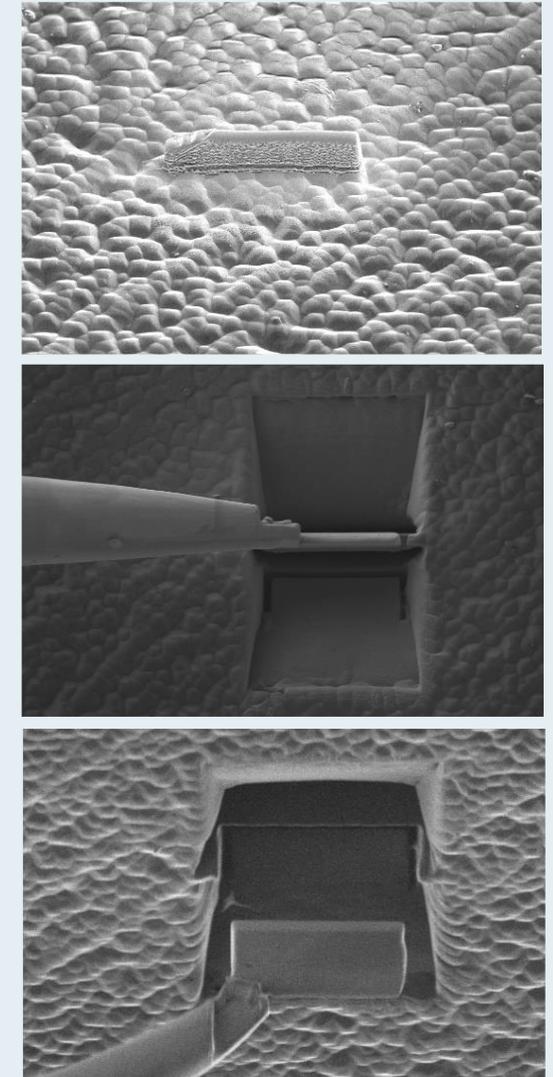
Approach

- Defects are localized by SEM
- Region of interest is cut out by FIB and lifted out with a micromanipulator
- Ion-milling with low-voltage Ar ions to minimize surface damage or implantation

Application

- Site-specific preparation of grain boundaries or defects with nm-resolution
- Preparation of electron-transparent TEM lamellae (< 100 nm)
- 3D imaging (slice-and-view) in SEM

Lift-out of a TEM lamella



Metrology for Thin Layers

Microscopical methods

TEM

Due to the sensitivity of the materials, sample preparation and TEM analysis is especially challenging.

Sample preparation

- FIB cuts perpendicular to the surface
- Direct deposition on electron-transparent substrates

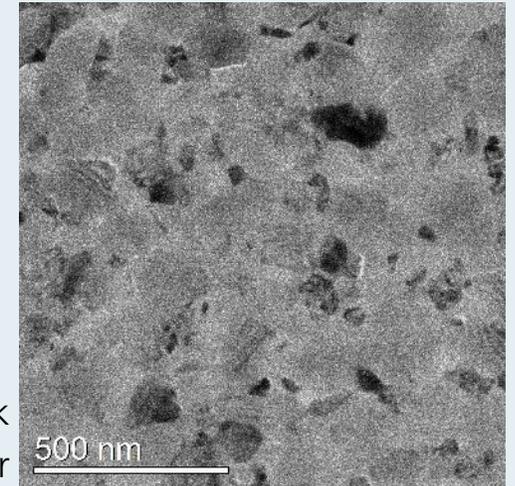
Measurements

- TEM and STEM for direct imaging of electron transparent samples
- Electron diffraction for analysis of crystalline materials
- EDX for quantitative elemental composition and mapping

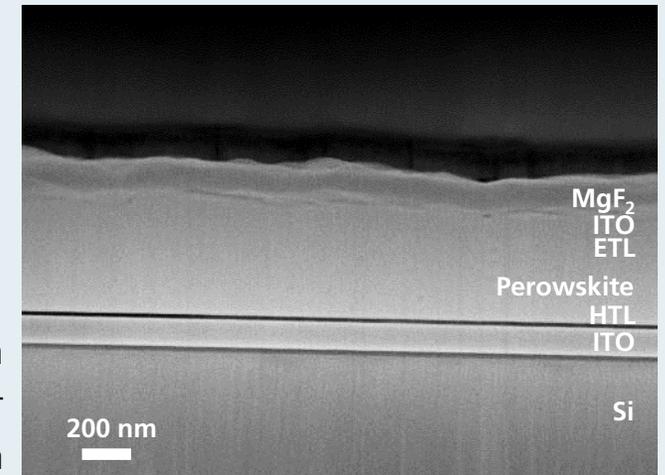
Application

- Investigation of layer stacks (side view), e.g. on a large sample's edges
- Direct imaging of layers (top view) for determination of internal structure
- Determination of layer thickness with nm-resolution

Direct imaging by electron microscopy



TEM of a 50 nm thick perovskite layer



STEM on a multilayer system

Metrology for Thin Layers

Surface Analysis

Photoelectron spectroscopy

XPS is a surface-sensitive technique for quantitative chemical analysis.

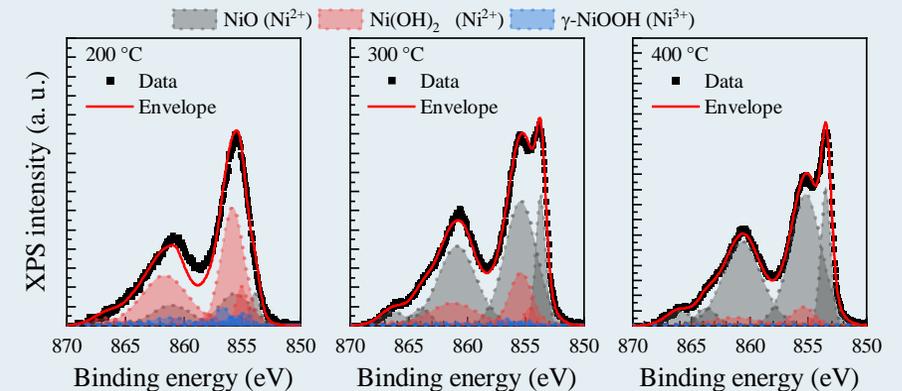
Approach

- Inert sample transfer to the XPS system to avoid air contact
- Determination of chemical elements and their oxidation states
- Coupling with sputter process for depth profiles
- Lateral resolution 50 μm , depth resolution 5 nm

Application

- Layer analysis for detailed understanding of a material's composition
- Monitoring of chemical reactions: Changes in a metal's oxidation states (e.g. during thermal conversion of a precursor)
- Detection of impurities (e.g. silicon from a sealant)

XPS monitors the conversion of a nickel oxide precursor



Detail spectra of the core level Ni $2p_{3/2}$ transitions of wet-chemically deposited and annealed NiO_x layers.

Metrology for Thin Layers

Surface Analysis

ToF-SIMS

Time-of-flight mass spectrometry is a sensitive method for detection of elements and molecules.

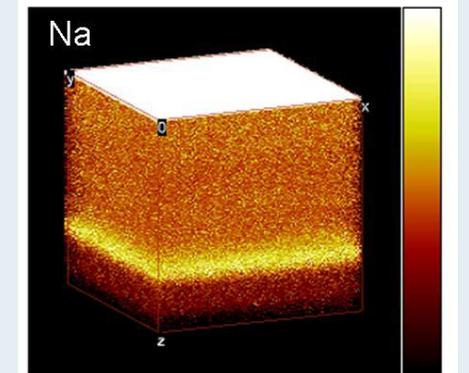
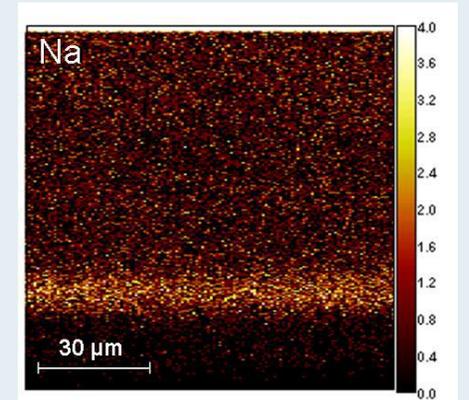
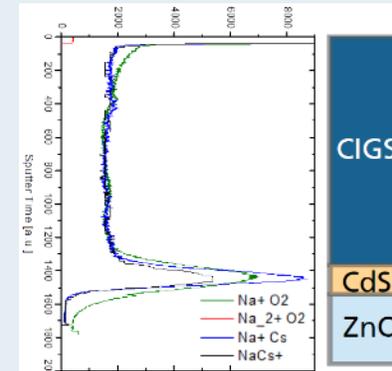
Approach

- Inert transfer to the ToF-SIMS system avoids sample contamination
- Analysis with ppb-sensitivity (10^{15} atoms per cm^3), lateral resolution of 0.2–5 μm and depth resolution of 10 nm
- Quantitative analysis by comparison with standards

Applications

- Identification of elements and chemical compounds
- 3D reconstruction by combination of depth profil and 2D mapping

3D reconstruction of Na within a CIGS sample by ToF-SIMS



Metrology for Thin Layers

Optical methods

HSI

Hyperspectral imaging a fast non-contact method for detecting lateral uniformity of optical properties.

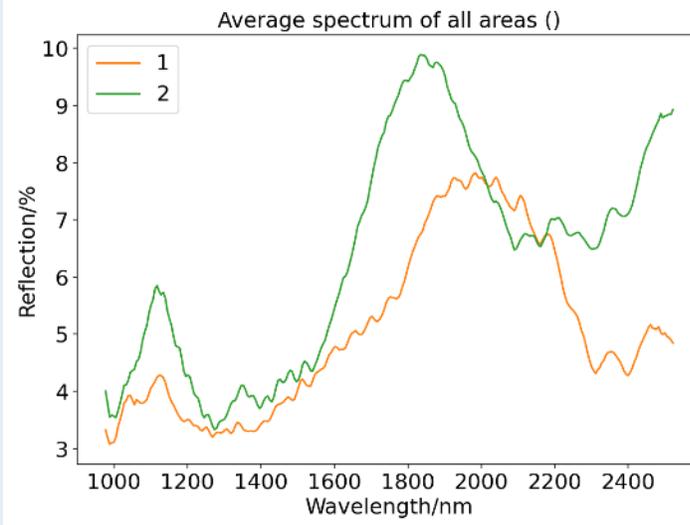
Approach

- Hyperspectral optical imaging in VNIR (400–1000 nm) or SWIR (1000–2500 nm) range (reflection)
- Data analysis using automated machine learning algorithms (classification, clustering ...) and data visualization (spectra, false-color RGB, color-overlays)

Applications

- Detection of lateral non-uniformities in a sample by spectral fingerprint
- Detection of sample-to-sample variations
- Suitable for in-line applications

Optical spectra of two samples from the same production line



Contact

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Fraunhofer ISE



Processing of Pero-Si-tandem solar cells

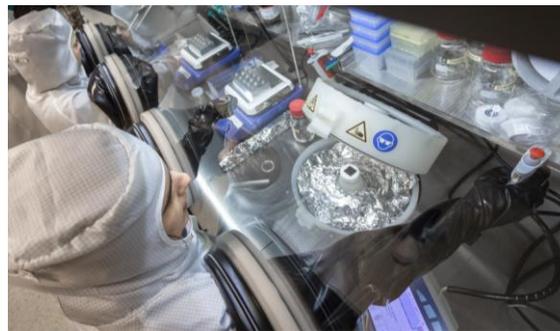
PeroLab – Wetchemical Processing

Processing Infrastructure @ISE



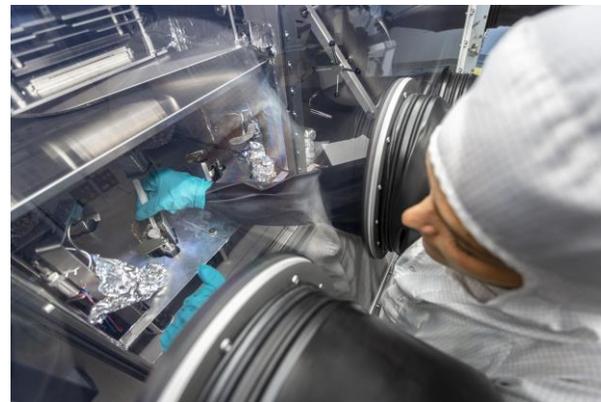
Wetchemical Processing

- 4 Gloveboxes with separated atmospheres:
GS Glovebox Systemtechnik
- Precision Scales
- Stirring Equipment
- Hot Plates
- Spin-Coater
- Slot-Die Coater (from Feb 2023)
- UV/Ozone Chamber



PeroLab – Vacuum&Hybrid Processing

Processing Infrastructure @ISE



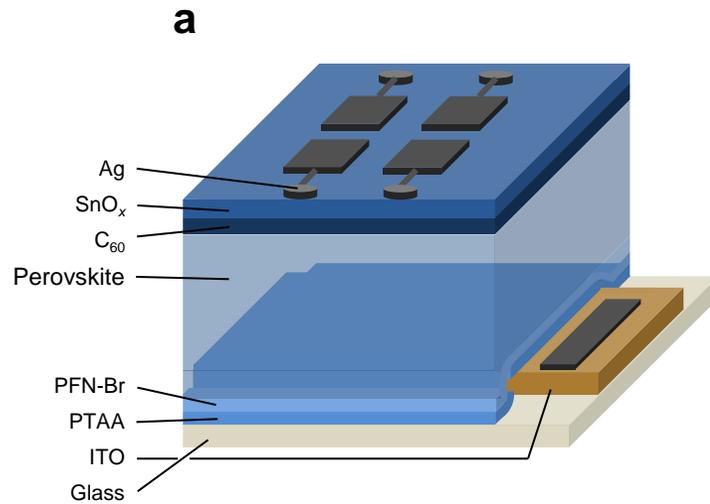
Vacuum Processing

- **4 Gloveboxes:** Mbraun
- **Evaporation Chamber for Perovskites:**
Creaphys 4 LTE sources
- **Evaporation Chamber for Metals & Metal Oxides:** Creaphys E-Gun / 2 Thermal Sources
- **Evaporation Chamber for Contact Materials & Organics:**
Creaphys 2 LTE / 2 Thermal Sources
- **Atomic Layer Deposition:** Arradance
- **Spin-Coater** for Hybrid Route

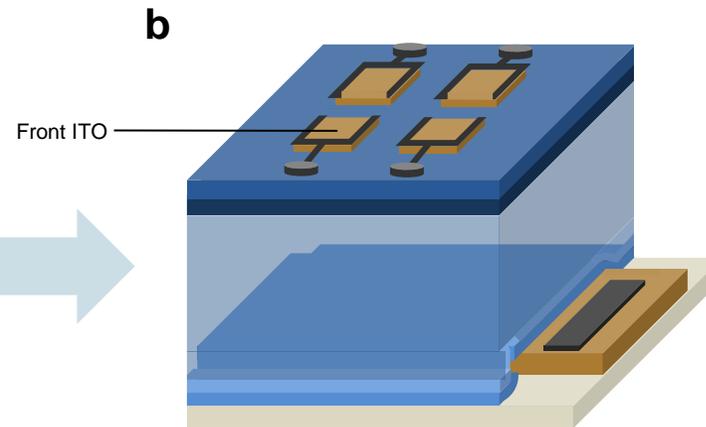
From Single-Junction to Tandem Solar Cells

Main Focus on Monolithic 2-Terminal Perovskite Silicon Tandem Solar Cells

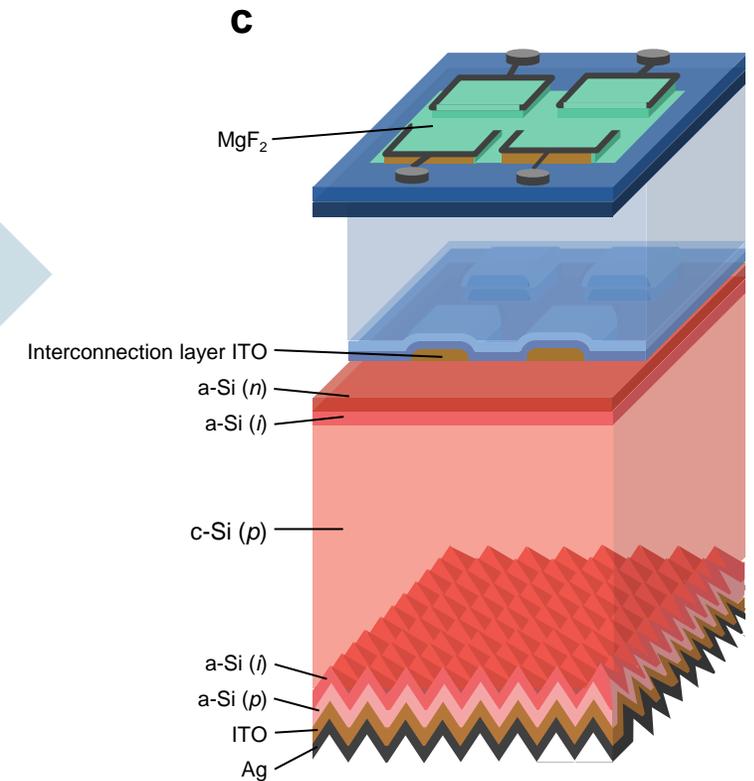
Opaque S-J PSC



Semitransparent S-J PSC



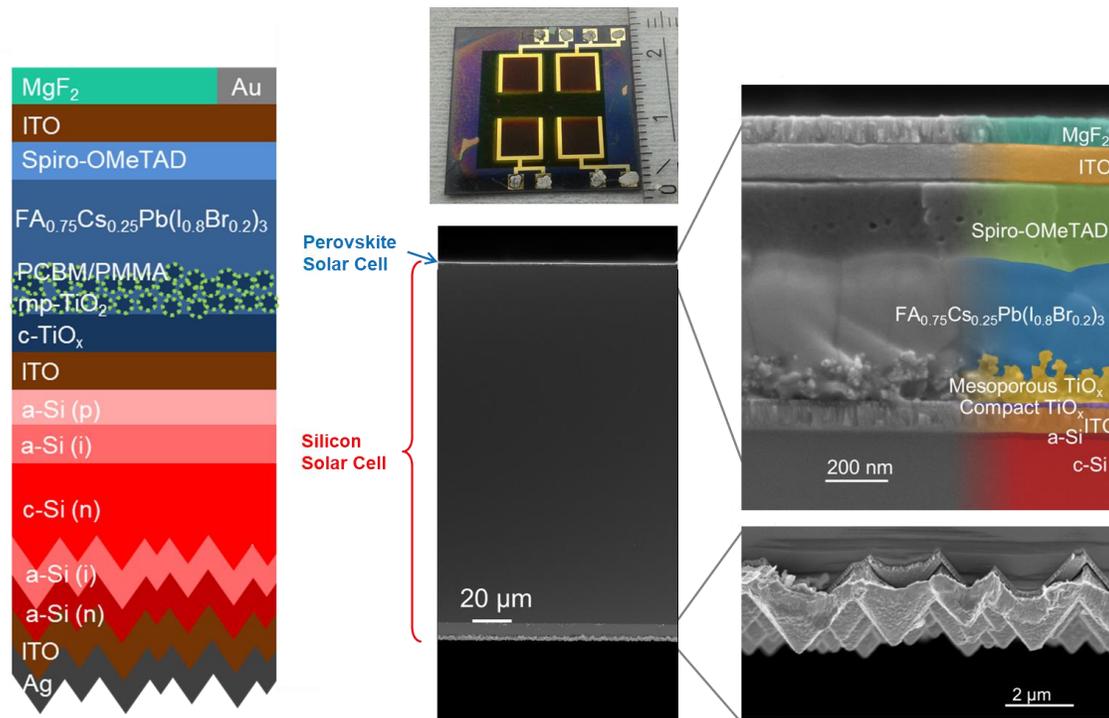
Monolithic 2T Pero-Si Tandem



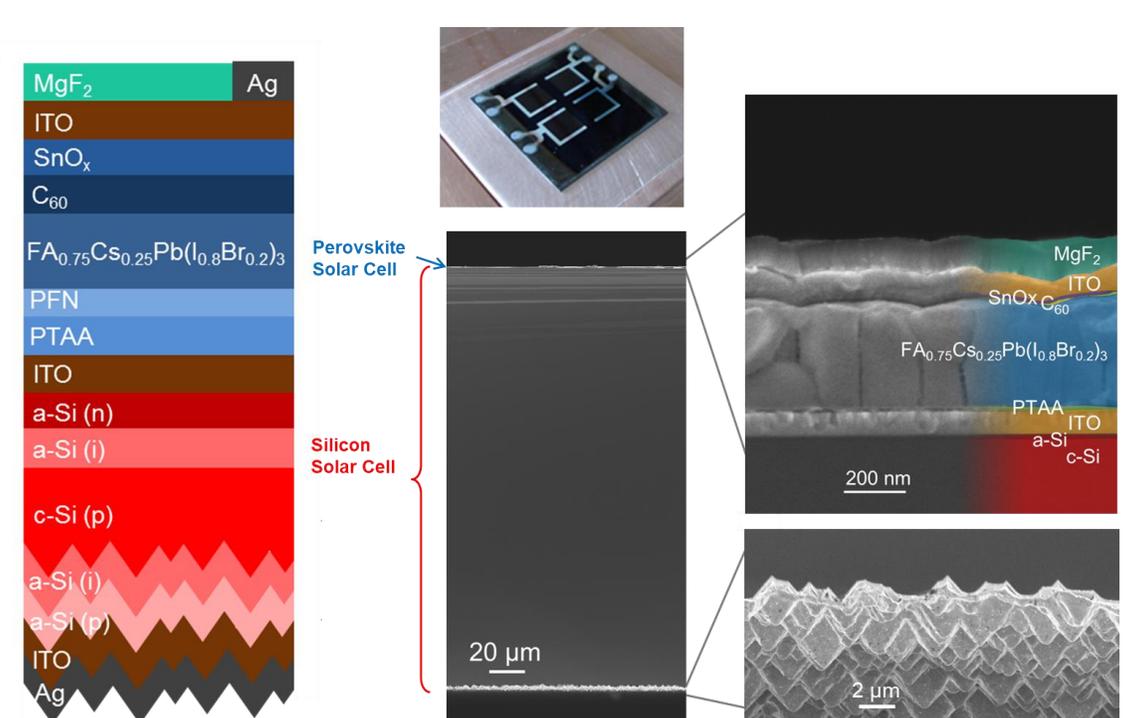
Tandem Device Architectures

Examples Realized at ISE

n-i-p Tandem



p-i-n Tandem

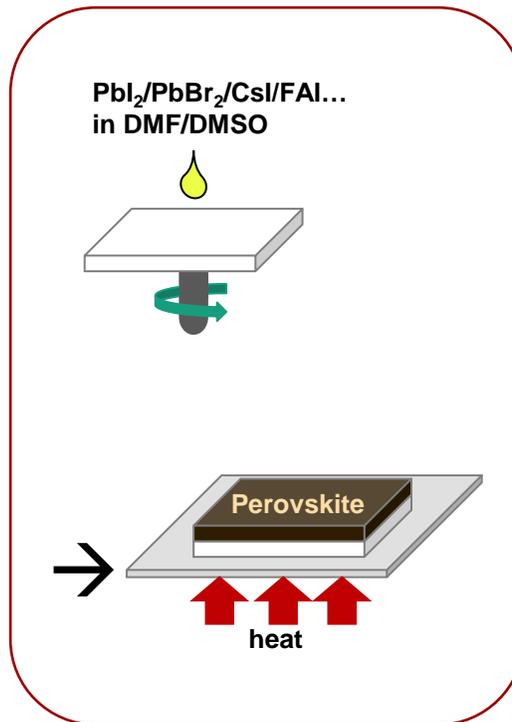


Pero-Si Tandem Processing Routes

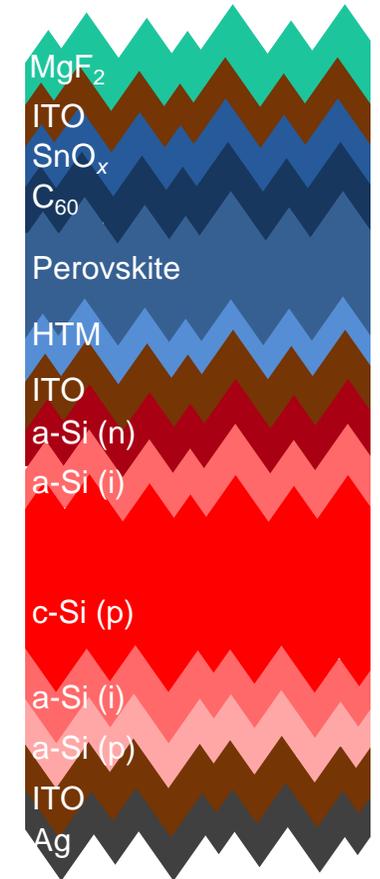
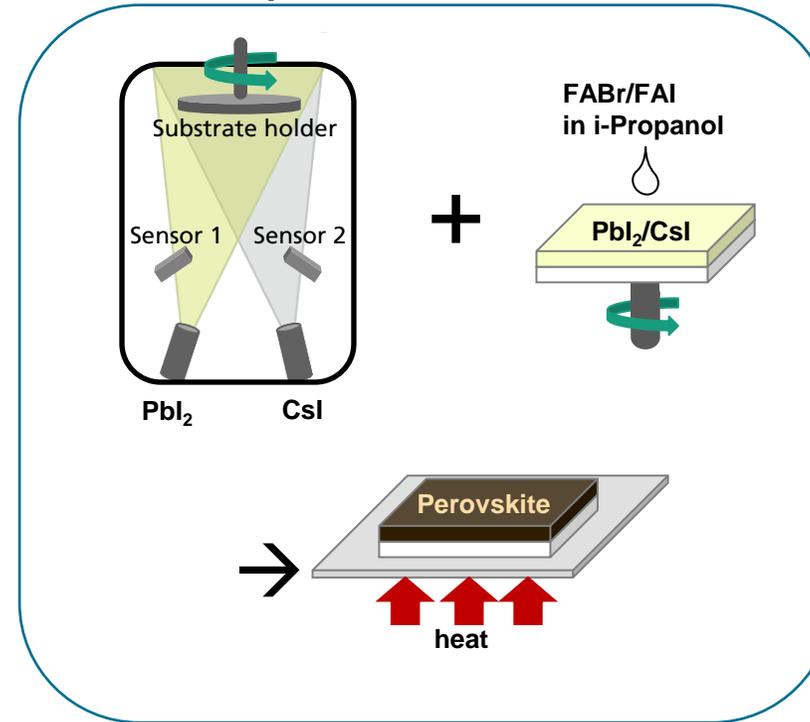
Main Routes for Top-Cell Processing in PeroLabs



1-Step Route Wetchemical



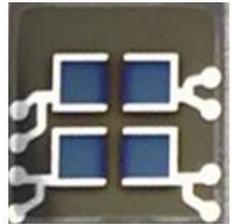
2-Step Hybrid Route Co-Evaporation+Wetchemical



Pero-Si Tandem Upscaling

From Substrate to Full Wafer Processing

25 mm



5 mm

25 mm

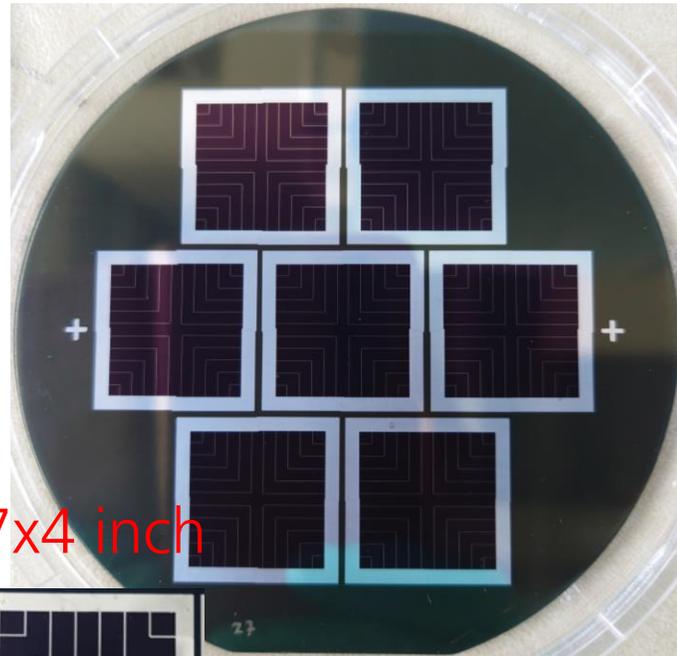


10 mm

7x4 inch



20 mm



Contact

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Perovskite and Perovskite-Tandem PV at Fraunhofer ISE & Fraunhofer CSP

How to work with us

- <https://www.viperlab-kep.eu/infrastructure.asp>
https://www.viperlab-kep.eu/infrastructure.asp?i=10&t=FRAUNHOFER__Solar_Cell_Manufacturing_&_Characterization



FRAUNHOFER Solar Cell Manufacturing & Characterization

Solar cell manufacturing & characterization

- High efficiency silicon bottom cells
- Vacuum and wet chemical processing of layers for perovskite tandem solar cells
- Metallisation concepts
- Electrical and optical analyses of perovskite silicon tandem cells and precursors
- High resolution analyses down to the nano scale

Organisation : FRAUNHOFER

Perovskite and Perovskite-Tandem PV at Fraunhofer ISE & Fraunhofer CSP

What is a promising proposal?

- You have promising samples with some pre-characterization which you would like to bring for in-depth analysis
 - The samples are stable enough that they survive the traveling

or

- You have a good idea for sample processing or analysis

- The work contains a new and exciting aspect
- There is a clear path towards further exploitation of the results, e.g. in joint publications



FRAUNHOFER - Solar Cell Manufacturing & Characterization

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More information at
Viperlab.eu
FULLY CONNECTED VIRTUAL AND PHYSICAL
PEROVSKITE PHOTOVOLTAICS LAB

